

# Technical Data Sheet 5mm Silicon Phototransistor T-1 3/4

## PT534-6B



#### **Features**

- Fast response time
- High photo sensitivity
- Pb free

#### **Descriptions**

 PT534-6B is a high speed and high sensitive NPN silicon phototransistor molded in a standard φ5 mm package.
 Due to its black epoxy the device is sensitive to visible and near infrared radiation..

## **Applications**

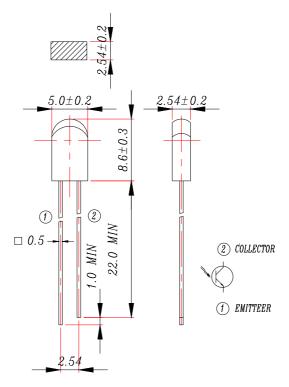
- Camera
- Infrared applied system

#### **Device Selection Guide**

LED Dowt No	Chip	Long Color	
LED Part No.	Material	Lens Color	
PT	Silicon	Black	



## **Package Dimensions**



**Notes:** 1.All dimensions are in millimeters

2.Tolerances unless dimensions ±0.1mm

## **Absolute Maximum Ratings (Ta=25°C)**

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	$V_{CEO}$	30	V
Emitter-Collector-Voltage	$V_{ECO}$	5	V
Collector Current	$I_{\mathrm{C}}$	20	mA
Operating Temperature	Topr	-40 ~ +85	$^{\circ}\!\mathbb{C}$
Storage Temperature	Tstg	-40 ~ +100	$^{\circ}\!\mathbb{C}$
Lead Soldering Temperature	Tsol	260	$^{\circ}\!\mathbb{C}$
Power Dissipation at (or			
below)	Pc	75	mW
25°C Free Air Temperature			

**Notes:** \*1:Soldering time  $\leq$  5 seconds.

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## **Electro-Optical Characteristics** (Ta=25 $^{\circ}$ C)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Collector – Emitter Breakdown Voltage	BV <sub>CEO</sub>	$I_C=100 \mu A$ $Ee=0mW/cm^2$	30			V
Emitter-Collector Breakdown Voltage	BV <sub>ECO</sub>	$I_E=100 \mu A$ $Ee=0mW/cm^2$	5			V
Collector-Emitter Saturation Voltage	V <sub>CE)(sat)</sub>	I <sub>C</sub> =2mA Ee=1mW/cm <sup>2</sup>			0.4	V
Rise Time	t <sub>r</sub>	V <sub>CE</sub> =5V I <sub>C</sub> =1mA		15		μS
Fall Time	$t_{f}$	$RL=1000\Omega$		15		
Collector Dark Current	I <sub>CEO</sub>	Ee=0mW/cm <sup>2</sup> V <sub>CE</sub> =20V			100	nA
On State Collector Current	$I_{C(on)}$	Ee=1mW/cm <sup>2</sup> V <sub>CE</sub> =5V	0.7	1.2		mA
Wavelength of Peak Sensitivity	λp			980		nm
Rang of Spectral Bandwidth	λ 0.5			800-1200		nm

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## **Typical Electro-Optical Characteristics Curves**

Fig.1Collector Power Dissipation vs.

Ambient Temperature

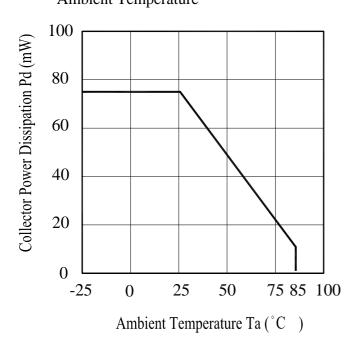


Fig.2 Spectral Sensitivity

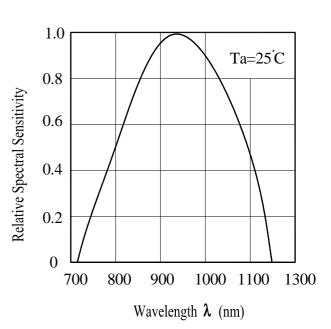


Fig.3 Relative Collector Current vs.

Ambient Temperature

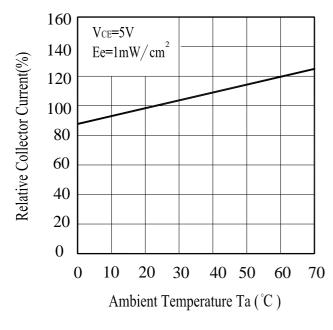
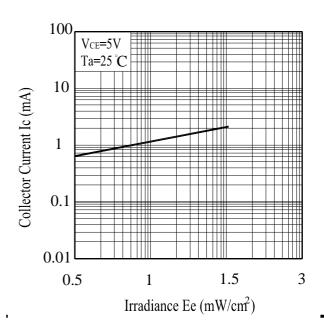


Fig.4 Collector Current vs.
Irradiance



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## **Typical Electro-Optical Characteristics Curves**

Fig.5 Collector Dark Current vs.

Ambient Temperature

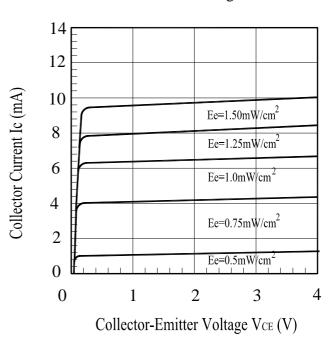
10<sup>-6</sup>
5
VCE=20V

2
OBJ 10<sup>-7</sup>
10<sup>-8</sup>
5
10<sup>-8</sup>
5
10<sup>-9</sup>
10
0 25 50 75 10C

Ambient Temperature Ta (°C)

Fig.6 Collector Current vs.

Collector-Emitter Voltage



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## **Reliability Test Item And Condition**

The reliability of products shall be satisfied with items listed below.

Confidence level: 90%

LTPD: 10%

NO.	Item	Test Conditions	Test Hours/	Sample	Failure	Ac/Re
			Cycles	Sizes	Judgement	
					Criteria	
1	Solder Heat	TEMP. : 260°C±5°C	10secs	22pcs		0/1
2	Temperature Cycle	$H:+100^{\circ}C$ 15mins	50Cycles	22pcs	$I_{C(ON)} \leq L \times 0.8$	0/1
		5mins				
		L:-40°C 15mins			L: Lower	
3	Thermal Shock	H :+100°C <b>▲</b> 5mins	50Cycles	22pcs	Specification	0/1
		↓ 10secs			Limit	
		L:- $10^{\circ}$ C 5mins				
4	High Temperature	TEMP. : +100°C	1000hrs	22pcs		0/1
	Storage					
5	Low Temperature	TEMP. : -40°C	1000hrs	22pcs		0/1
	Storage					
6	DC Operating Life	V <sub>CE</sub> =5V	1000hrs	22pcs		0/1
7	High Temperature/	85°C / 85% R.H	1000hrs	22pcs		0/1
	High Humidity					

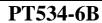
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#### **Packing Quantity Specification**

- 1. 500Pcs/Bags , 6Bags/1Boxes
- 2. 10Boxes/1Carton

#### **Label Form Specification**



CPN: Customer's Production Number

P/N : Production Number QTY: Packing Quantity

CAT: Ranks

HUE: Peak Wavelength

**REF:** Reference

LOT No: Lot Number

#### **Notes**

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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